

Low Capacitance, Low Charge Injection, 4- / 8-Channel, Triple SPDT, $\pm 5\text{ V}$ / 12 V / 5 V / 3 V Analog Multiplexers

DESCRIPTION

The DGQ4051E, DGQ4052E, and DGQ4053E are high precision CMOS analog multiplexers. The DGQ4051E is an 8-channel multiplexer, the DGQ4052E is a dual 4-channel multiplexer, and the DGQ4053E is a triple 2-channel multiplexer or triple SPDT.

The DGQ4051E, DGQ4052E, and DGQ4053E feature low leakage, parasitic capacitance, and low charge injection of 0.3 pC over the full voltage range. These devices are ideal for high precision signal switching and multiplexing.

Designed to operate from a 3 V to 16 V single supply or from a $\pm 3\text{ V}$ to $\pm 8\text{ V}$ dual supplies, the DGQ4051E, DGQ4052E, and DGQ4053E are fully specified at 3 V, 5 V, 12 V and $\pm 5\text{ V}$. All control logic inputs have guaranteed 2 V logic high limit when operating from 5 V or $\pm 5\text{ V}$ supplies and 1.4 V when operating from a 3 V supply.

All switches conduct equally well in both directions, offering rail to rail analog signal switching and can be used both as multiplexers as well as de-multiplexers.

The DGQ4051E, DGQ4052E, and DGQ4053E operating temperature is specified from $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$ and are available in 16 pin TSSOP package.

BENEFITS

- Wide operation voltage range
- Low charge injection
- Low parasitic capacitance
- Compact package option

FEATURES

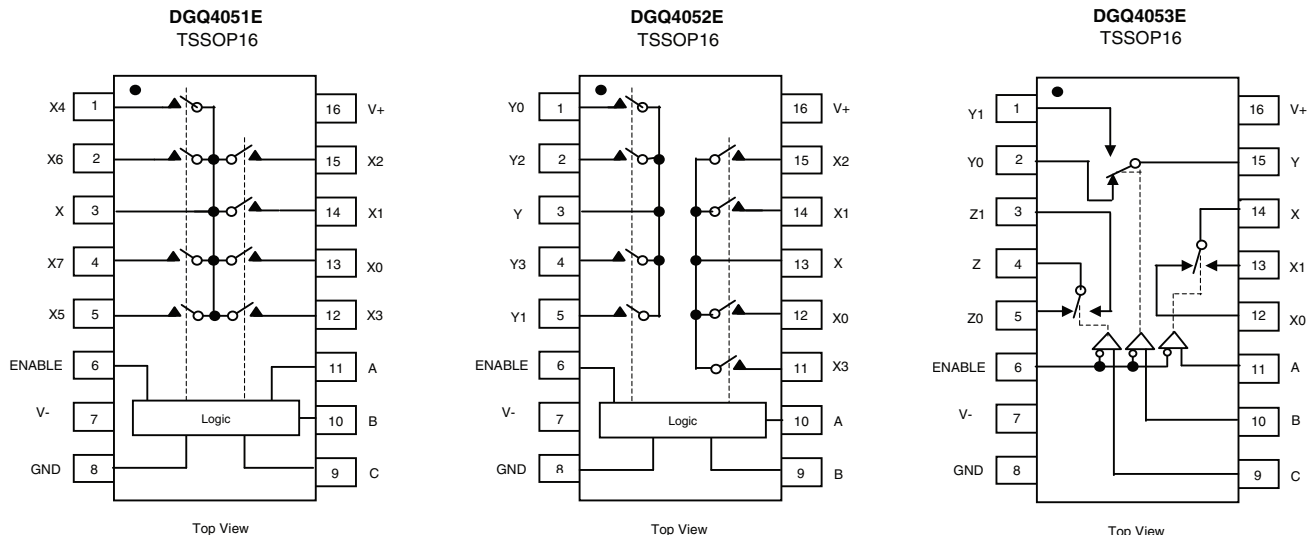
- Automotive product AEC-Q100 qualified (Grade 1)
- Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ and from $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$
- 3 V to 16 V single supply or ± 3 to $\pm 8\text{ V}$ dual supply operation
- Low parasitic capacitance:
 $C_{D(ON)}$: 8.5 pF / typ. (DGQ4053E)
 $C_{S(OFF)}$: 2.0 pF / typ. (DGQ4053E)
- Less than 0.3 pC charge injection over the full signal swing range
- Low leakage: $< 50\text{ pA}$, typ.
- Fast switching t_{ON} : 35 ns, typ.
- 3 V logic compatible for control
- Bi-directional rail to rail signal switching
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
COMPLIANT

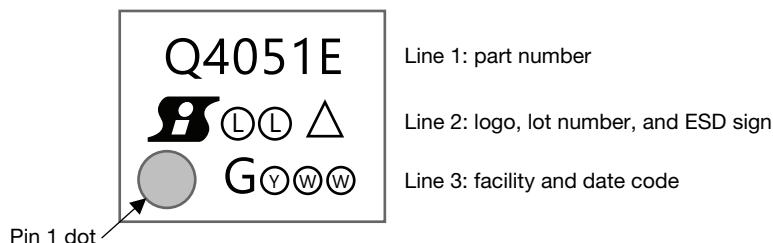
APPLICATIONS

- Automotive battery management systems
- Automotive infotainment and telematics
- Automotive analog and digital signal multiplexing / demultiplexing

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



ENABLE = LO, all switches are controlled by addr pins.
 ENABLE = HI, all switches are off.

MARKING INFORMATION

TRUTH TABLE

ENABLE INPUT	SELECT INPUTS			ON SWITCHES		
	C	B	A	DGQ4051E	DGQ4052E	DGQ4053E
H	X	X	X	All switches open	All switches open	All switches open
L	L	L	L	X to X0	X to X0, Y to Y0	X to X0, Y to Y0, Z to Z0
L	L	L	H	X to X1	X to X1, Y to Y1	X to X1, Y to Y0, Z to Z0
L	L	H	L	X to X2	X to X2, Y to Y2	X to X0, Y to Y1, Z to Z0
L	L	H	H	X to X3	X to X3, Y to Y3	X to X1, Y to Y1, Z to Z0
L	H	L	L	X to X4	X to X0, Y to Y0	X to X0, Y to Y0, Z to Z1
L	H	L	H	X to X5	X to X1, Y to Y1	X to X1, Y to Y0, Z to Z1
L	H	H	L	X to X6	X to X2, Y to Y2	X to X0, Y to Y1, Z to Z1
L	H	H	H	X to X7	X to X3, Y to Y3	X to X1, Y to Y1, Z to Z1

ORDERING INFORMATION

ORDERING PART NUMBER	CONFIGURATION	MARKING	TEMPERATURE RANGE	PACKAGE	MIN. ORDER / PACKAGING QUANTITY
DGQ4051EEQ-T1-GE4	8:1 x 1	Q4051E	-40 °C to +125 °C ^a	16-pin TSSOP	Tape and reel 3000 units
DGQ4052EEQ-T1-GE4	4:1 x 2	Q4052E			
DGQ4053EEQ-T1-GE4	2:1 x 3	Q4053E			

Note

a. -40 °C to +85 °C datasheet limits apply

ABSOLUTE MAXIMUM RATINGS ($T_A = 25\text{ °C}$, unless otherwise noted)

PARAMETER	LIMIT	UNIT
V+ to V-	-0.3 to +18	V
GND to V-	-18	
Digital inputs ^a , V _S , V _D	(V-) - 0.3 to (V+) + 0.3 or 30 mA, whichever occurs first	
Continuous current (any terminal)	30	mA
Peak current, S or D (pulsed 1 ms, 10 % duty cycle)	100	
Storage temperature	-65 to +150	°C
Power dissipation ^b	16-pin TSSOP ^c	mW
Thermal resistance ^b	16-pin TSSOP ^c	°C/W
ESD human body model (HBM); per AEC-Q100-002	2000	V
ESD charged device model (CDM), per AEC-Q100-011	750	V
Latch up current, per AEC-100-004 (JEDEC® class II)	100	mA

Notes

- a. Signals on SX, DX, or INX exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings
- b. All leads welded or soldered to PC board
- c. Derate 5.6 mW/°C above 70 °C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



SPECIFICATIONS FOR DUAL SUPPLIES

PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 5 V, V- = -5 V VIN(A, B, C, and enable) = 2 V, 0.8 V ^a	TEMP. ^b	TYP. ^c	-40 °C to +125 °C		-40 °C to +85 °C		UNIT	
					MIN. ^d	MAX. ^d	MIN. ^d	MAX. ^d		
Analog Switch										
Analog signal range ^e	V _{ANALOG}		Full	-	-5	5	-5	5	V	
On-resistance	R _{ON}	I _S = 1 mA, V _D = -3 V, 0 V, 3 V	Room	68	-	78	-	78	Ω	
			Full	-	-	106	-	97		
On-resistance match	ΔR _{ON}	I _S = 1 mA, V _D = ± 3 V	Room	0.91	-	6	-	6		
			Full	-	-	6	-	6		
On-resistance flatness	R _{FLATNESS}	I _S = 1 mA, V _D = -3 V, 0 V, 3 V	Room	10	-	17	-	17		
			Full	-	-	20	-	19		
Switch off leakage current	I _{S(off)}	V+ = 5.5 V, V- = -5.5 V, V _D = ± 4.5 V, V _S = ∓ 4.5 V	Room	± 0.05	-1	1	-1	1	nA	
	Full		-	-50	50	-5	5			
	I _{D(off)}		Room	± 0.05	-1	1	-1	1		
			Full	-	-50	50	-5	5		
Channel on leakage current	I _{D(on)}	V+ = 5.5 V, V- = -5.5 V, V _S = V _D = ± 4.5 V	Room	± 0.05	-1	1	-1	1		
			Full	-	-50	50	-5	5		
Digital Control										
Input current, V _{IN} low	I _{IL}	V _{IN} (A, B, C, and enable) under test = 0.6 V	Full	0.02	-1	1	-1	1	μA	
Input current, V _{IN} high	I _{IH}	V _{IN} (A, B, C, and enable) under test = 2 V	Full	0.02	-1	1	-1	1		
Input capacitance ^e	C _{IN}	f = 1 MHz	Room	3.4	-	-	-	-	pF	
Dynamic Characteristics										
Off isolation ^e	OIRR	R _L = 50 Ω, C _L = 1 pF	f = 100 kHz	Room	-106	-	-	-	dB	
			f = 10 MHz	Room	-68	-	-	-		
			f = 100 MHz	Room	-49	-	-	-		
Channel-to-channel crosstalk ^e	X _{TALK}		f = 100 kHz	Room	-105	-	-	-		
			f = 10 MHz	Room	-62	-	-	-		
			f = 100 MHz	Room	-51	-	-	-		
Bandwidth, 3 dB	BW	R _L = 50 Ω	DGQ4051E	Room	308	-	-	-	MHz	
			DGQ4052E	Room	353	-	-	-		
			DGQ4053E	Room	930	-	-	-		
Transition time	t _{TRANS}	R _L = 300 Ω, C _L = 35 pF see Fig. 1, 2, 3	Room	72	-	112	-	112	ns	
			Full	-	-	139	-	131		
Enable turn-on time	t _{ON}		Room	35	-	75	-	75		
			Full	-	-	86	-	80		
Enable turn-off time	t _{OFF}		Room	48	-	88	-	88		
			Full	-	-	97	-	95		
Break-before-make time delay	t _D		Room	-	1	-	1	-		
			Full	-	-	-	-	-		
Charge injection ^e	Q	V _g = 0 V, R _g = 0 Ω, C _L = 1 nF	Room	0.38	-	-	-	-	pC	
Source off capacitance ^e	C _{S(off)}	f = 1 MHz	DGQ4051E	Room	2.2	-	-	-	pF	
			DGQ4052E	Room	2.1	-	-	-		
			DGQ4053E	Room	2	-	-	-		
Drain off capacitance ^e	C _{D(off)}	f = 1 MHz	DGQ4051E	Room	9.2	-	-	-		
			DGQ4052E	Room	4.8	-	-	-		
			DGQ4053E	Room	3.1	-	-	-		
Channel on capacitance ^e	C _{D(on)}	f = 1 MHz	DGQ4051E	Room	14.9	-	-	-		
			DGQ4052E	Room	10	-	-	-		
			DGQ4053E	Room	8.5	-	-	-		
Total harmonic distortion ^e	THD	Signal = 5 V _{RMS} , 20 Hz to 20 kHz, R _L = 600 Ω	Room	0.065	-	-	-	-	%	

**SPECIFICATIONS FOR DUAL SUPPLIES**

PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 5 V, V- = -5 V VIN(A, B, C, and enable) = 2 V, 0.8 V ^a	TEMP. ^b	TYP. ^c	-40 °C to +125 °C		-40 °C to +85 °C		UNIT
					MIN. ^d	MAX. ^d	MIN. ^d	MAX. ^d	
Power Supplies									
Power supply current	I+	V+ = 5 V, V- = -5 V VIN(A, B, C, and enable) = 0 V or 5 V	Room	0.05	-	1	-	1	μA
			Full	-	-	10	-	10	
Negative supply current	I-		Room	-0.05	-1	-	-1	-	
			Full	-	-10	-	-10	-	
Ground current	IGND		Room	-0.05	-1	-	-1	-	
			Full	-	-10	-	-10	-	

SPECIFICATIONS FOR UNIPOLAR SUPPLIES

PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 12 V, V- = 0 V VIN(A, B, C, AND ENABLE) = 2 V, 0.8 V A	TEMP. b	TYP. c	-40 °C to +125 °C		-40 °C to +85 °C		UNIT
					MIN. d	MAX. d	MIN. d	MAX. d	
Analog Switch									
Analog signal Range e	VANALOG		Full	-	0	12	0	12	V
On-resistance	RON	IS = 1 mA, VD = 0.7 V, 11.3 V	Room	85	-	103	-	103	Ω
			Full	-	-	133	-	125	
On-resistance match	ΔRON	IS = 1 mA, VD = 11.3 V	Room	1.24	-	8	-	8	Ω
			Full	-	-	8	-	8	
On-resistance flatness	RFLATNESS	IS = 1 mA, VD = 0.7 V, 11.3 V	Room	27	-	37	-	37	Ω
			Full	-	-	44	-	43	
Switch off leakage current	IS(off)	V+ = 13.2 V, V- = 0 V VD = 1 V / 12.2 V, VS = 12.2 V / 1 V	Room	± 0.05	-1	1	-1	1	nA
			Full	-	-50	50	-5	5	
	ID(off)		Room	± 0.05	-1	1	-1	1	
			Full	-	-50	50	-5	5	
Channel on leakage current	ID(on)	V+ = 13.2 V, V- = 0 V VD = VS = 1 V / 12.2 V	Room	± 0.05	-1	1	-1	1	nA
			Full	-	-50	50	-5	5	
Digital Control									
Input current, VIN low	IL	VIN(A, B, C, and enable) under test = 0.8 V	Full	0.02	-1	1	-1	1	μA
Input current, VIN high	IH	VIN(A, B, C, and enable) under test = 2 V	Full	0.02	-1	1	-1	1	
Dynamic Characteristics									
Transition time	tTRANS	RL = 300 Ω, CL = 35 pF see Fig. 1, 2, 3	Room	43	-	83	-	83	ns
			Full	-	-	95	-	90	
Enable turn-on ime	tON		Room	22	-	62	-	62	
			Full	-	-	71	-	67	
Enable turn-off time	tOFF		Room	47	-	87	-	87	
			Full	-	-	94	-	93	
Break-before-make time delay	tD		Room	25	1	-	1	-	
			Full	-	-	-	-	-	
Charge injection e	Q	Vg = 0 V, Rg = 0 Ω, CL = 1 nF	Full	-	-	-	-	-	pC
Off isolation e	OIRR	RL = 50 Ω, CL = 1 pF f = 100 kHz	Room	-	-	-	-	-	dB
Channel-to-channel crosstalk e	XTALK		Room	-	-	-	-	-	

**SPECIFICATIONS FOR UNIPOLAR SUPPLIES**

PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 12 V, V- = 0 V VIN(A, B, C, AND ENABLE) = 2 V, 0.8 V A		TEMP. b	TYP. c	-40 °C to +125 °C		-40 °C to +85 °C		UNIT
						MIN. d	MAX. d	MIN. d	MAX. d	
Dynamic Characteristics										
Source off capacitance e	CS(off)	f = 1 MHz	DGQ4051E	Room	-	-	-	-	-	pF
			DGQ4052E	Room	-	-	-	-	-	
			DGQ4053E	Room	-	-	-	-	-	
Drain off capacitance e	CD(off)	f = 1 MHz	DGQ4051E	Room	-	-	-	-	-	
			DGQ4052E	Room	-	-	-	-	-	
			DGQ4053E	Room	-	-	-	-	-	
Channel on capacitance e	CD(on)	f = 1 MHz	DGQ4051E	Room	-	-	-	-	-	
			DGQ4052E	Room	-	-	-	-	-	
			DGQ4053E	Room	-	-	-	-	-	
Power Supplies										
Power supply current	I+	VIN(A, B, C, and enable) = 0 V or 5 V		Room	0.05	-	1	-	1	μA
Negative supply current	I-			Full	-	-	10	-	10	
				Room	-0.05	-1	-	-1	-	
Ground current	IGND			Full	-	-10	-	-10	-	
				Room	-0.05	-1	-	-1	-	
				Full	-	-10	-	-10	-	

SPECIFICATIONS FOR UNIPOLAR SUPPLIES

PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 5 V, V- = 0 V VIN(A, B, C, and enable) = 2 V, 0.8 V ^a	TEMP. ^b	TYP. ^c	-40 °C to +125 °C		-40 °C to +85 °C		UNIT
					MIN. ^d	MAX. ^d	MIN. ^d	MAX. ^d	
Analog Switch									
Analog signal range ^e	VANALOG		Full	-	0	5	0	5	V
On-resistance	RON	IS = 1 mA, VD = 0 V, 3.5 V	Room	125	-	147	-	147	Ω
			Full	-	-	176	-	168	
On-resistance match	ΔRON	IS = 1 mA, VD = 3.5 V	Room	1.3	-	8	-	8	
			Full	-	-	8	-	8	
On-resistance flatness	RFLATNESS	IS = 1 mA, VD = 0 V, 3 V	Room	21	-	31	-	31	nA
			Full	-	-	25	-	29	
Switch off leakage current	IS(off)	V+ = 5.5 V, V- = 0 V VD = 1 V / 4.5 V, VS = 4.5 V / 1 V	Room	± 0.03	-1	1	-1	1	
			Full	-	-50	50	-5	5	
	ID(off)		Room	± 0.03	-1	1	-1	1	
			Full	-	-50	50	-5	5	
Channel on leakage current	ID(on)	V+ = 5.5 V, V- = 0 V VD = VS = 1 V / 4.5 V	Room	± 0.03	-1	1	-1	1	
			Full	-	-50	50	-5	5	
Digital Control									
Input current, VIN low	IL	VIN(A, B, C, and enable) under test = 0.6 V	Full	0.02	-1	1	-1	1	μA
Input current, VIN high	IH	VIN(A, B, C, and enable) under test = 2 V	Full	0.02	-1	1	-1	1	



SPECIFICATIONS FOR UNIPOLAR SUPPLIES

PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 5 V, V- = 0 V VIN(A, B, C, and enable) = 2 V, 0.8 V a		TEMP. b	TYP. c	-40 °C to +125 °C		-40 °C to +85 °C		UNIT
						MIN. d	MAX. d	MIN. d	MAX. d	
Dynamic Characteristics										
Transition time	tTRANS	RL = 300 Ω, CL = 35 pF see Fig. 1, 2, 3		Room	95	-	135	-	135	ns
				Full	-	-	169	-	148	
Enable turn-on time	tON			Room	56	-	96	-	96	
				Full	-	-	117	-	107	
Enable turn-off time	tOFF			Room	55	-	95	-	95	
				Full	-	-	110	-	103	
Break-before-make time delay	tD			Room	-	12	-	12	-	
				Full	-	-	-	-	-	
Charge injection e	Q	Vg = 0 V, Rg = 0 Ω, CL = 1 nF		rull	0.32	-	-	-	-	pC
Off isolation e	OIRR	RL = 50 Ω, CL = 1 pF f = 100 kHz		Room	-86	-	-	-	-	dB
Channel-to-channel crosstalk e	XTALK			Room	-105	-	-	-	-	
Source off capacitance e	CS(off)	f = 1 MHz	DGQ4051E	Room	2.4	-	-	-	-	pF
			DGQ4052E	Room	2.4	-	-	-	-	
			DGQ4053E	Room	2.3	-	-	-	-	
Drain off capacitance e	CD(off)	f = 1 MHz	DGQ4051E	Room	10.1	-	-	-	-	
			DGQ4052E	Room	5.3	-	-	-	-	
			DGQ4053E	Room	3.4	-	-	-	-	
Channel on capacitance e	CD(on)	f = 1 MHz	DGQ4051E	Room	15.9	-	-	-	-	
			DGQ4052E	Room	10.6	-	-	-	-	
			DGQ4053E	Room	8.9	-	-	-	-	
Power Supplies										
Power supply current	I+	VIN(A, B, C, and enable) = 0 V or 5 V		Room	0.05	-	1	-	1	μA
				Full	-	-	10	-	10	
Negative supply current	I-			Room	-0.05	-1	-	-1	-	
				Full	-	-10	-	-10	-	
Ground current	IGND			Room	-0.05	-1	-	-1	-	
				Full	-	-10	-	-10	-	



SPECIFICATIONS FOR UNIPOLAR SUPPLIES

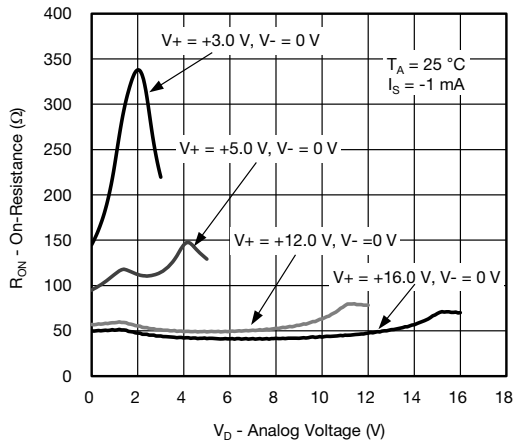
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V ₊ = 3 V, V ₋ = 0 V V _{IN(A, B, C, and enable)} = 1.4 V, 0.6 V ^a		TEMP. ^b	TYP. ^c	-40 °C to +125 °C		-40 °C to +85 °C		UNIT
						MIN. ^d	MAX. ^d	MIN. ^d	MAX. ^d	
Analog Switch										
Analog signal range ^e	V _{ANALOG}			Full	-	0	3	0	3	V
On-resistance	R _{ON}	I _S = 1 mA, V _D = 1.5 V		Room	221	-	-	-	-	Ω
				Full	-	-	-	-	-	
Switch off leakage current	I _{S(off)}	V ₊ = 3.3 V, V ₋ = 0 V V _D = 0.3 V / 3 V, V _S = 3 V / 0.3 V		Room	± 0.02	-1	1	-1	1	nA
				Full	-	-50	50	-5	5	
	I _{D(off)}			Room	± 0.02	-1	1	-1	1	
				Full	-	-50	50	-5	5	
Channel on leakage current	I _{D(on)}	V ₊ = 3.3 V, V ₋ = 0 V V _D = V _S = 0.3 V / 3 V		Room	± 0.02	-1	1	-1	1	
				Full	-	-50	50	-5	5	
Digital Control										
Input current, V _{IN} Low	I _L	V _{IN(A, B, C, and enable)} under test = 0.6 V		Full	0.02	-1	1	-1	1	μA
Input current, V _{IN} High	I _H	V _{IN(A, B, C, and enable)} under test = 1.4 V		Full	0.02	-1	1	-1	1	
Dynamic Characteristics										
Transition time	t _{TRANS}	R _L = 300 Ω, C _L = 35 pF see Fig. 1, 2, 3		Room	200	-	-	-	-	ns
Enable turn-on time	t _{ON}			Full	-	-	-	-	-	
				Room	130	-	-	-	-	
Enable turn-off time	t _{OFF}			Full	-	-	-	-	-	
				Room	78	-	-	-	-	
Break-before-make time delay	t _D			Full	-	-	-	-	-	
				Room	130	-	-	-	-	
Charge injection ^e	Q	V _g = 0 V, R _g = 0 Ω, C _L = 1 nF		Room	0.34	-	-	-	-	pC
Off isolation ^e	OIRR	R _L = 50 Ω, C _L = 1 pF f = 100 kHz		Room	-88	-	-	-	-	dB
Channel-to-channel crosstalk ^e	X _{TALK}			Room	-105	-	-	-	-	
Source off capacitance ^e	C _{S(off)}	f = 1 MHz	DGQ4051E	Room	2.6	-	-	-	-	pF
			DGQ4052E	Room	2.6	-	-	-	-	
			DGQ4053E	Room	2.5	-	-	-	-	
Drain off capacitance ^e	C _{D(off)}	f = 1 MHz	DGQ4051E	Room	10.7	-	-	-	-	
			DGQ4052E	Room	5.7	-	-	-	-	
			DGQ4053E	Room	3.6	-	-	-	-	
Channel on capacitance ^e	C _{D(on)}	f = 1 MHz	DGQ4051E	Room	16.4	-	-	-	-	
			DGQ4052E	Room	10.9	-	-	-	-	
			DGQ4053E	Room	9.1	-	-	-	-	
Power Supplies										
Power supply current	I ₊	V _{IN(A, B, C, and enable)} = 0 V or 3 V		Room	0.05	-	1	-	1	μA
				Full	-	-	10	-	10	
Negative supply current	I ₋			Room	-0.05	-1	-	-1	-	
				Full	-	-10	-	-10	-	
Ground current	I _{GND}			Room	-0.05	-1	-	-1	-	
				Full	-	-10	-	-10	-	

Notes

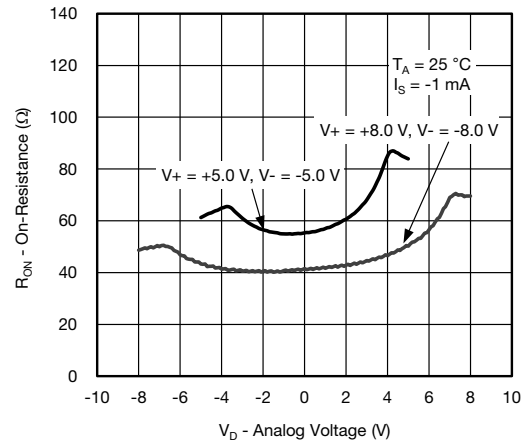
- a. V_{IN} = input voltage to perform proper function
b. Room = 25 °C, full = as determined by the operating temperature suffix
c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing
d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet
e. Guaranteed by design, not subject to production test



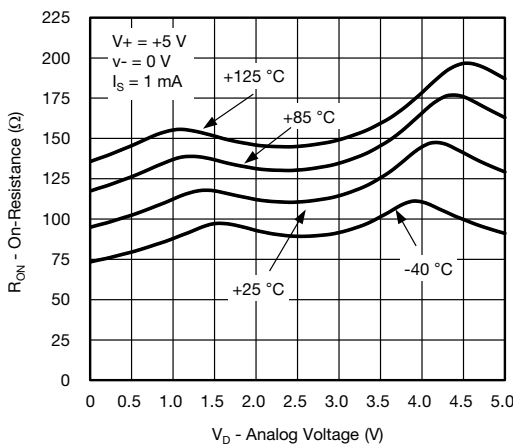
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



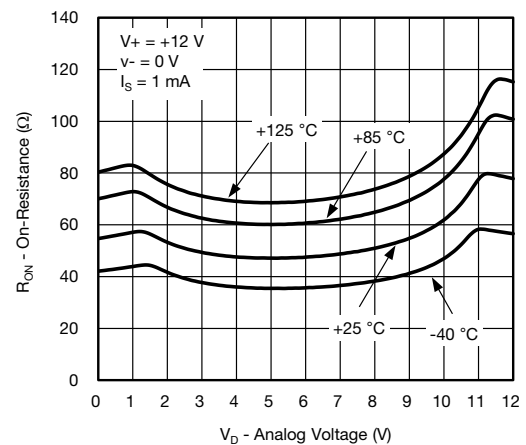
On-Resistance vs. Analog Voltage (Single Supply)



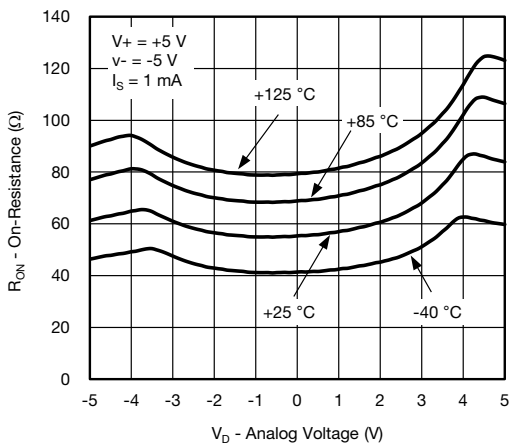
On-Resistance vs. Analog Voltage (Dual Supply)



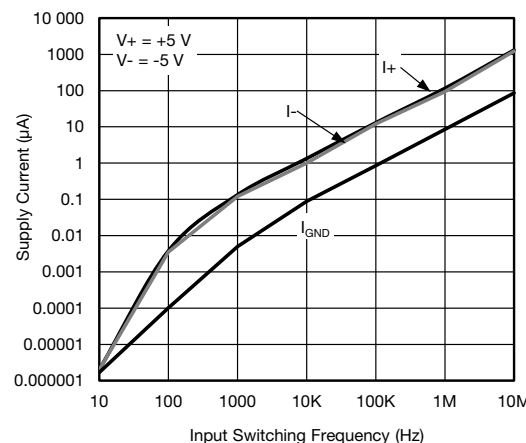
On-Resistance vs. Analog Voltage (Temperature)



On-Resistance vs. Analog Voltage (Temperature)



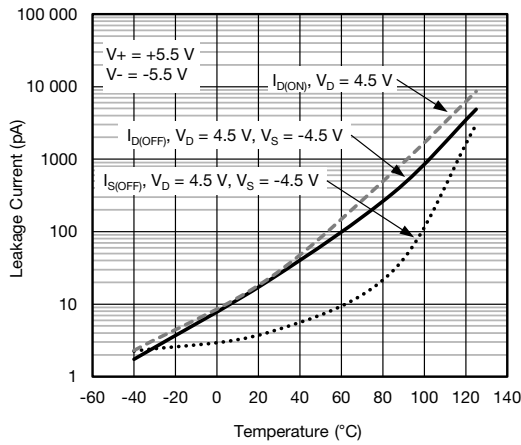
On-Resistance vs. Analog Voltage (Temperature)



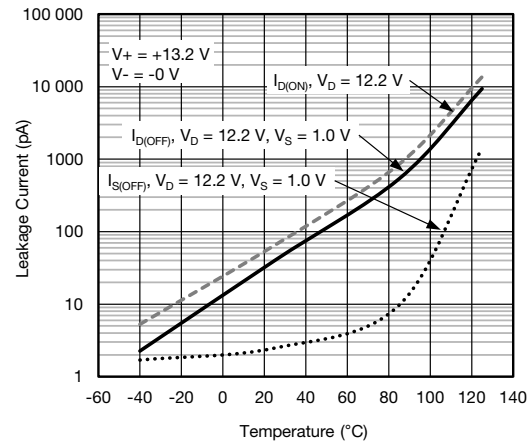
Supply Current vs. Input Switching Frequency



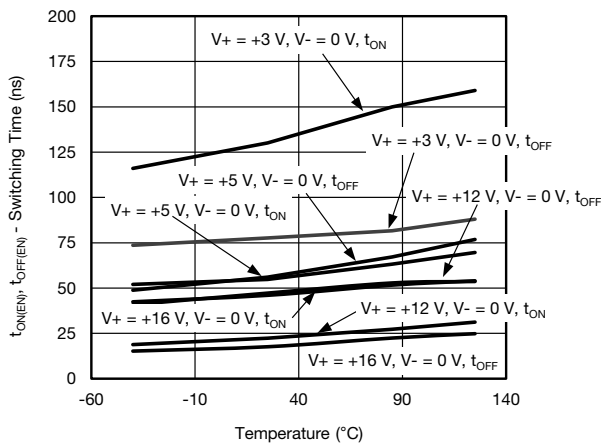
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



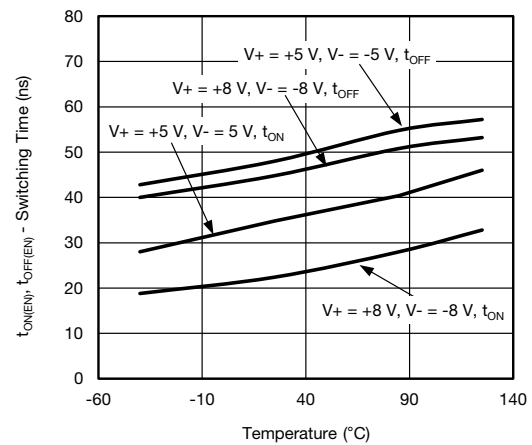
Leakage Current vs. Temperature



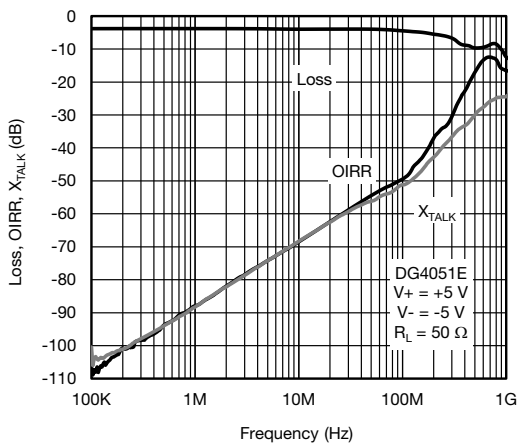
Leakage Current vs. Temperature



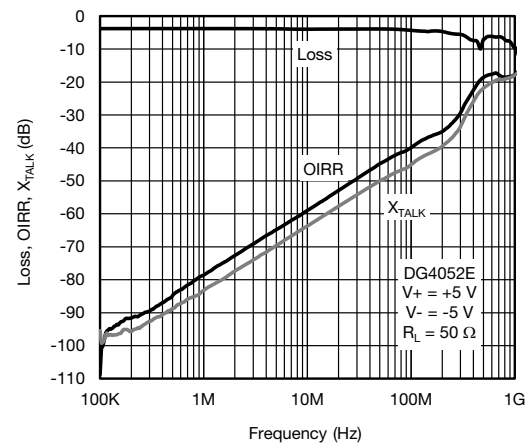
Switching Time vs. Temperature (Single Supply)



Switching Time vs. Temperature (Dual Supply)



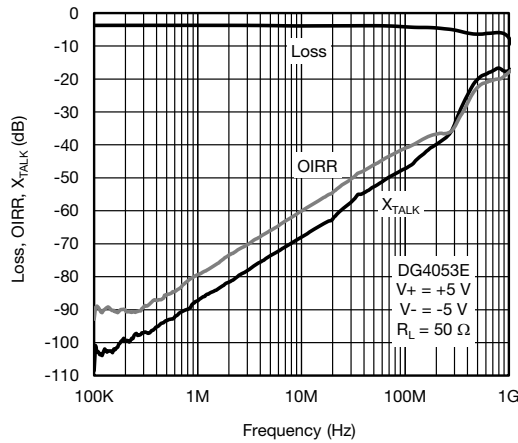
DGQ4051E Insertion Loss, Off-Isolation, Crosstalk vs. Frequency



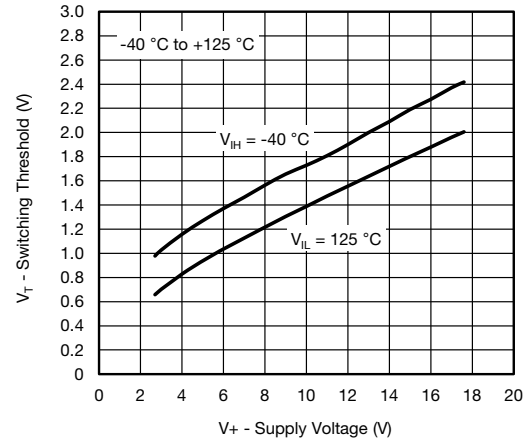
DGQ4052E Insertion Loss, Off-Isolation, Crosstalk vs. Frequency



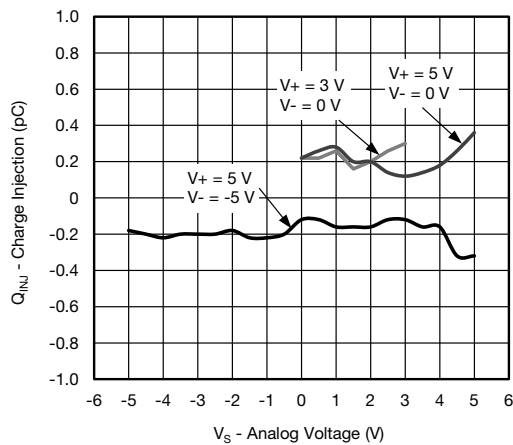
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



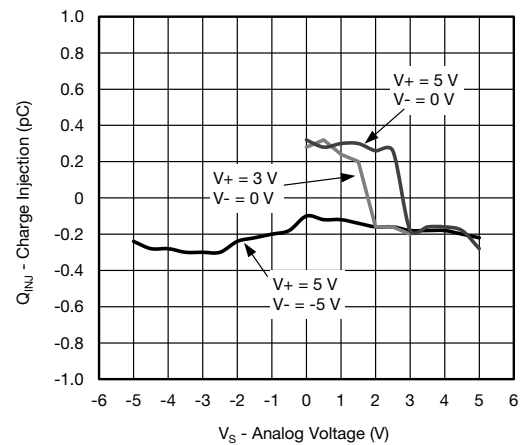
DGQ4053E Insertion Loss, Off-Isolation, Crosstalk vs. Frequency



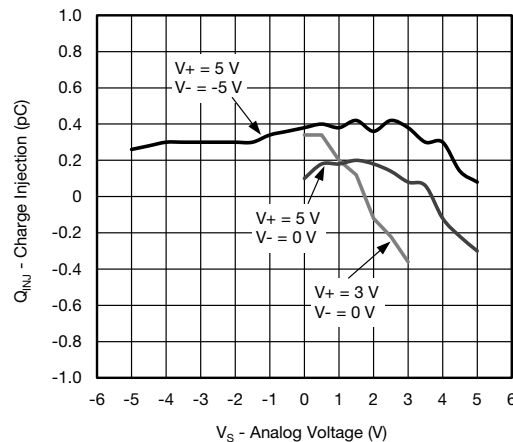
Switching Threshold vs. V_+ Supply Voltage



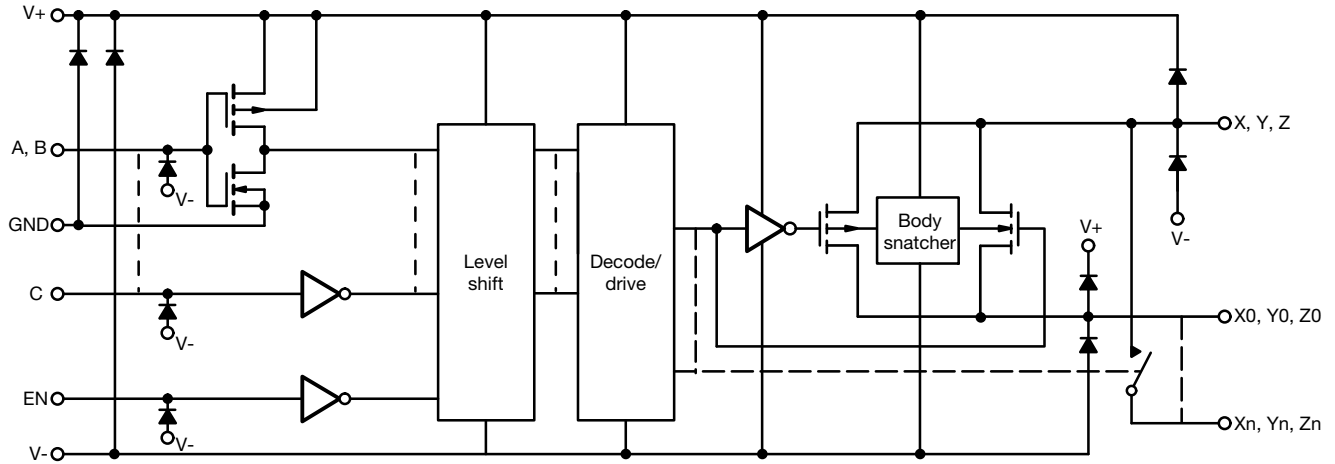
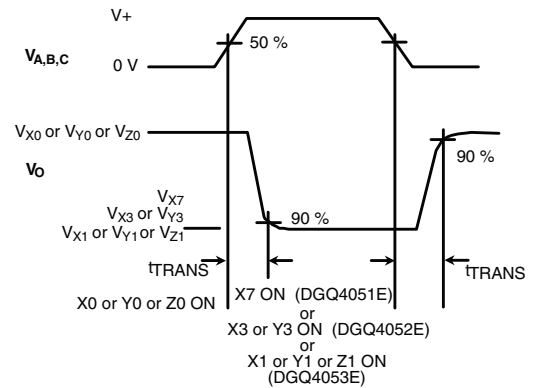
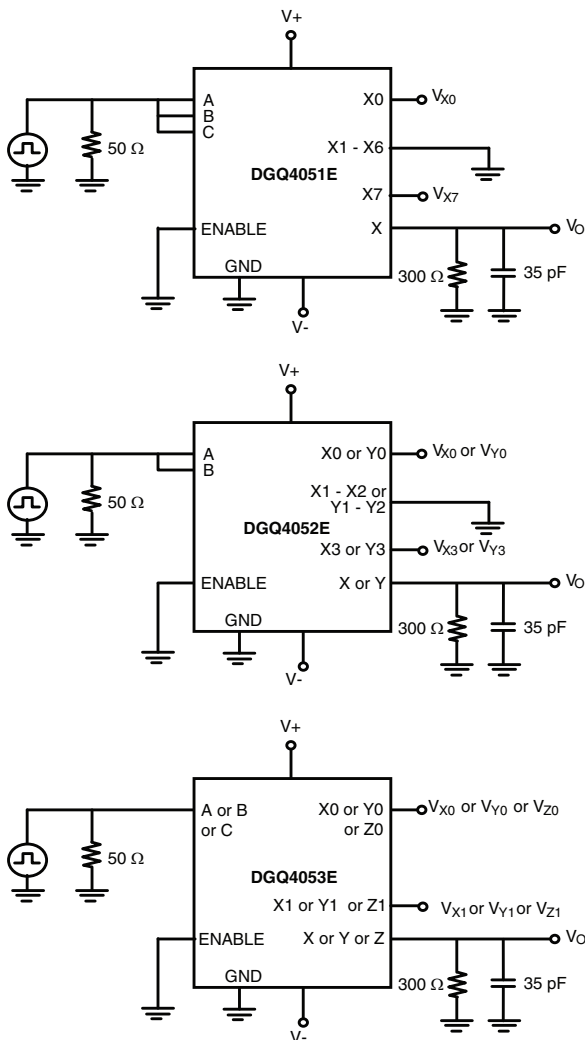
DGQ4051E Charge Injection vs. Analog Voltage

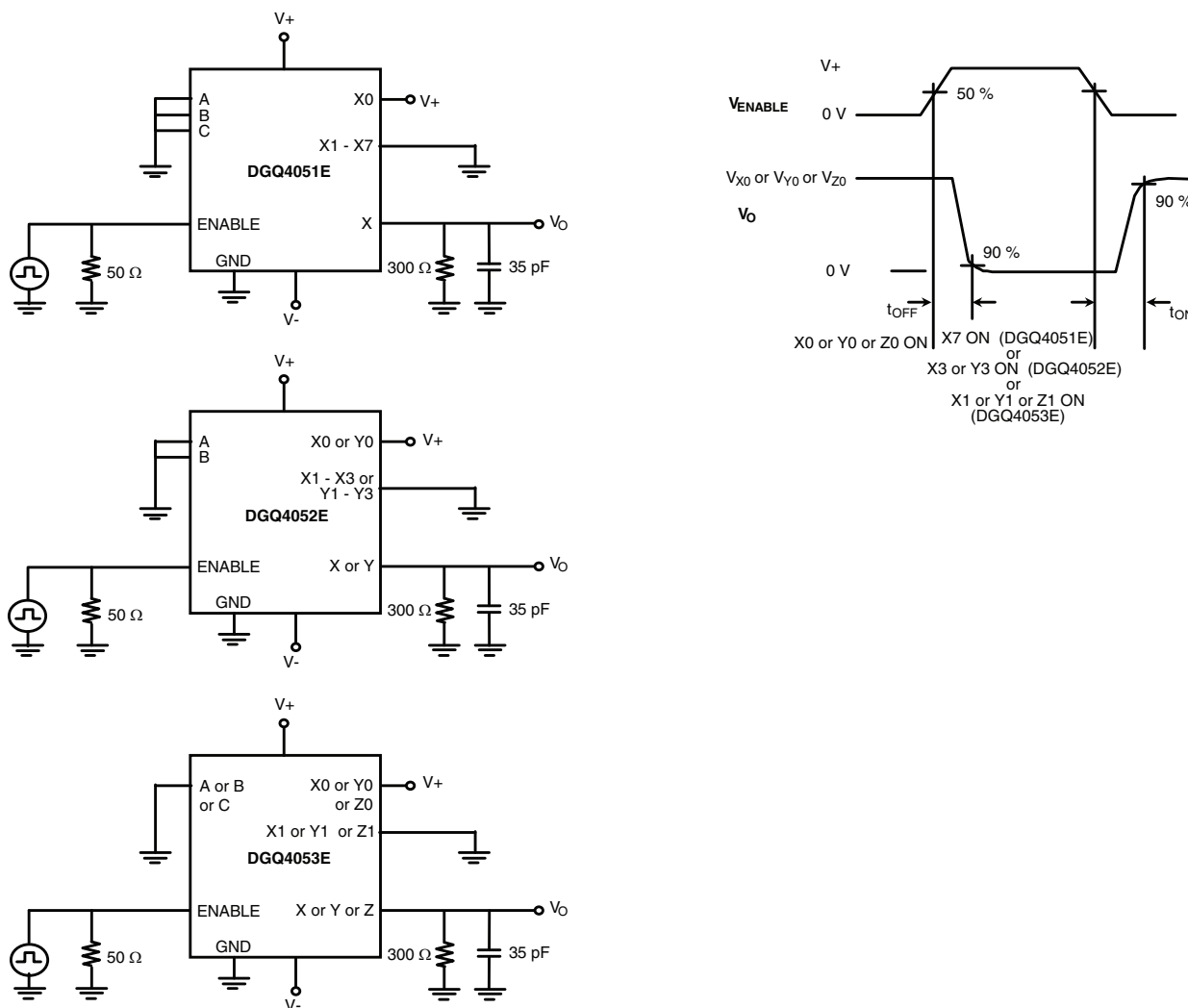


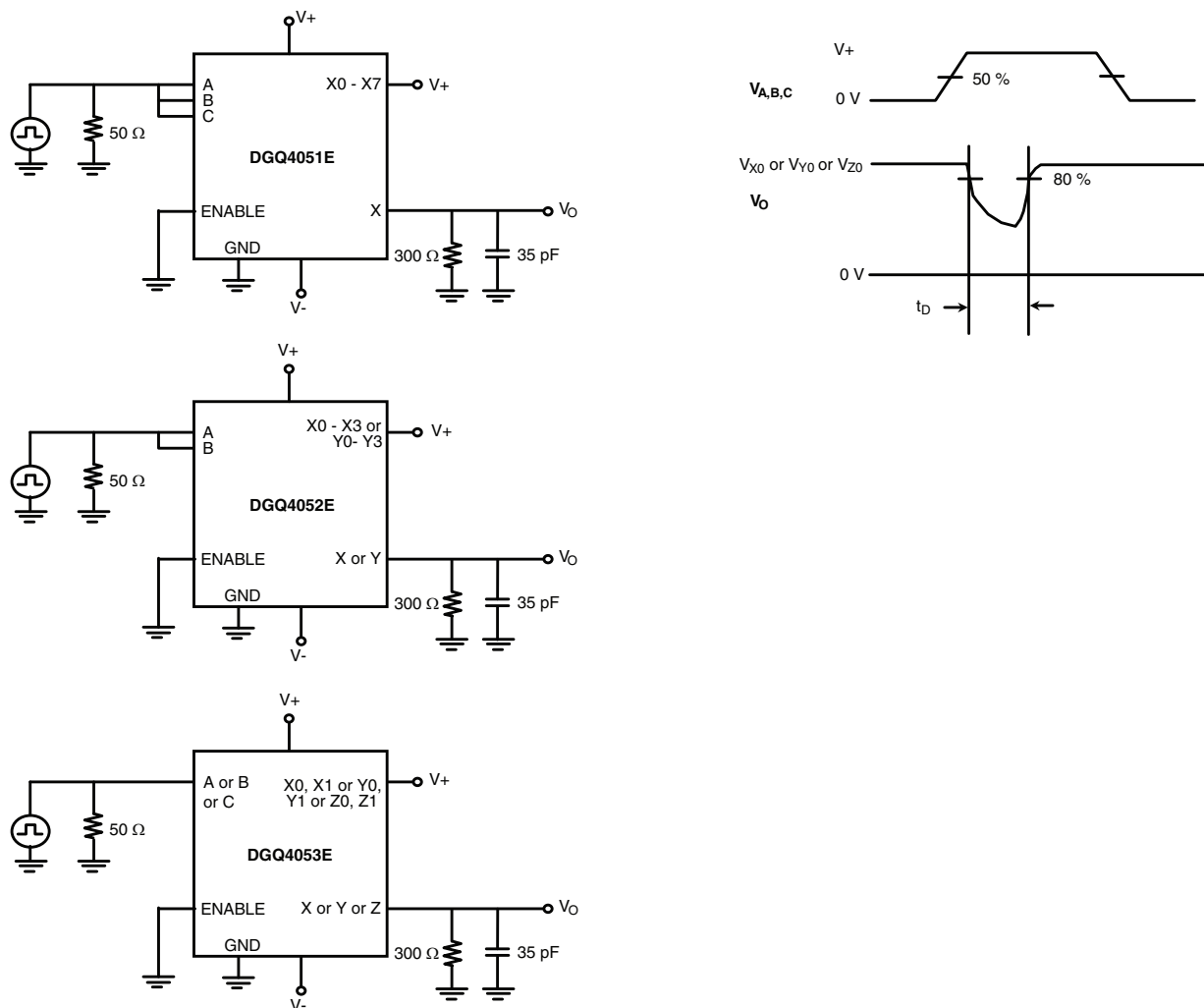
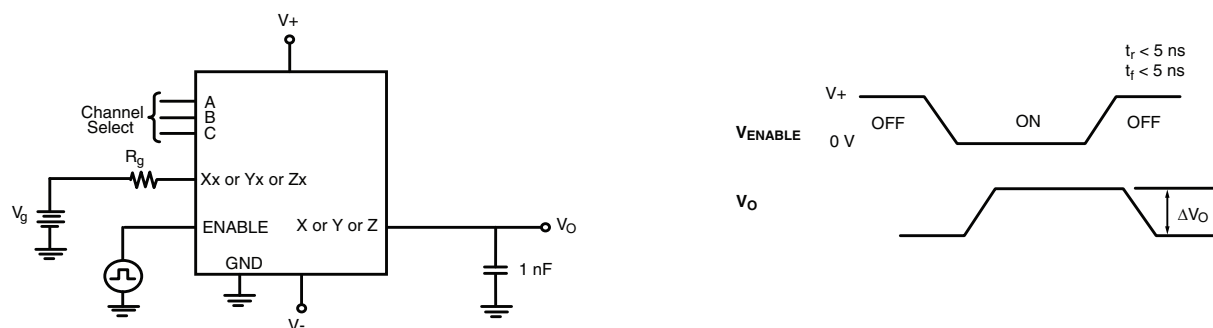
DGQ4053E Charge Injection vs. Analog Voltage

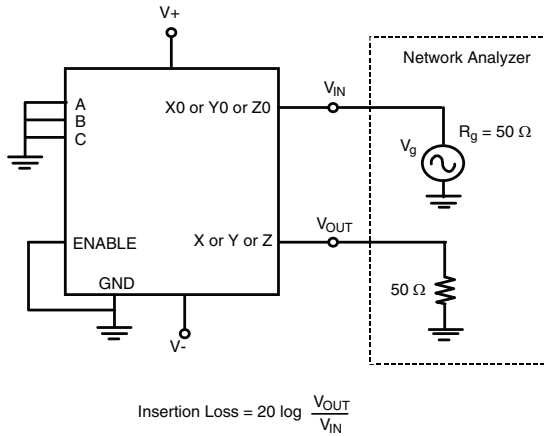
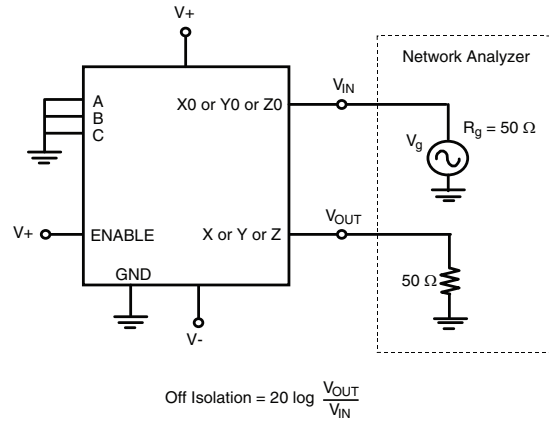
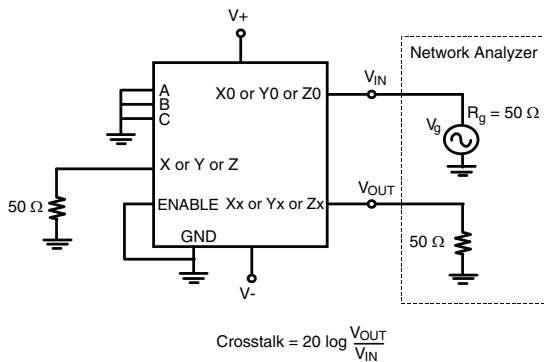
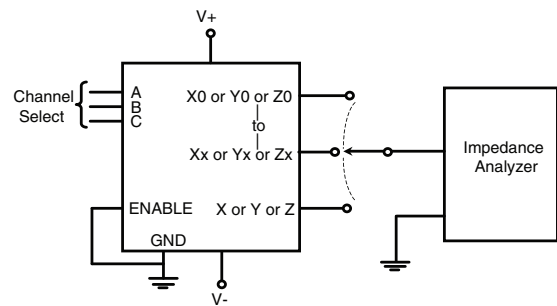


DGQ4052E Charge Injection vs. Analog Voltage

SCHEMATIC DIAGRAM (Typical Channel)

TEST CIRCUITS

Fig. 1 - Transition Time

TEST CIRCUITS

Fig. 2 - Enable Switching Time

TEST CIRCUITS

Fig. 3 - Break-Before-Make

Fig. 4 - Charge Injection

TEST CIRCUITS

Fig. 5 - Insertion Loss

Fig. 7 - Off Isolation

Fig. 6 - Crosstalk

Fig. 8 - Source, Drain Capacitance

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?79297.



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.